

Mini DomiLED

Synonymous with function and performance, the Mini DomiLED series is perfectly suited for a variety of cross-industrial applications due to its small package outline, durability and superior brightness.



Features:

- > High brightness surface mount LED.
- > 120° viewing angle.
- > Small package outline (LxWxH) of 2.0 x 1.4 x 1.3mm.
- > Qualified according to JEDEC moisture sensitivity Level 2.
- > Compatible to IR reflow soldering.
- > Environmental friendly; RoHS compliance.
- > Passed Corrosion Resistant Test. *Appx. 4.1*
- > Compliance to automotive standard; AEC-Q102.



Applications:

- > Automotive: interior applications, eg: switches, climate control system, dashboard, etc.



Optical Characteristics at Tj=25°C

Part Number	Color	Viewing Angle°	Luminous Intensity @ 20mA IV (mcd) <i>Appx. 1.1</i>		
			Min.	Typ.	Max.
● DNH-CJS-N2Q1-1	Hyper-red, 640nm	120	35.50	56.00	90.00
● DNS-CJS-PQ2-1	Super-red, 632nm	120	45.00	71.50	112.50
● DNS-CJS-Q2S1-1	Super-red, 632nm	120	90.00	140.00	224.00
● DNS-CJS-QR1-1	Super-red 632nm	120	71.50	105.00	140.00
● DNR-CJS-RS2-1	Red, 625nm	120	112.50	180.00	285.00
● DNA-CJS-RS2-1	Amber, 615nm	120	112.50	180.00	285.00
● DNO-CJS-RS2-1	Orange, 605nm	120	112.50	180.00	285.00
● DNO-CJS-S2T-1	Orange, 605nm	120	224.0	355.0	450.0
● DNY-CJS-RS2-1	Yellow, 587nm	120	112.50	180.00	285.00
● DNG-CJS-PQ2-1	Green, 570nm	120	45.00	71.50	112.50
● DNP-CJS-LM2-1	Pure Green, 560nm	120	11.20	18.00	28.50
● Not for new design					

Electrical Characteristics at Tj=25°C

Part Number	Vf @ If = 20mA <i>Appx. 3.1</i>			Vr @ Ir = 10uA <i>Appx. 6.1</i>
	Min. (V)	Typ. (V)	Max. (V)	Min. (V)
DNH-CJS, DNS-CJS, DNR-CJS, DNA-CJS, DNO-CJS, DNY-CJS, DNG-CJS, DNP-CJS	1.7	1.95	2.4	12

Absolute Maximum Ratings

	Maximum Value	Unit
DC forward current	30	mA
Peak pulse current; (Ts = 55°C, tp = 100µs, D = 0.03)	90	mA
Reverse voltage <i>Appx. 6.1</i>	12	V
ESD threshold (HBM)	2	KV
LED junction temperature	125	°C
Operating temperature	-40 ... +105	°C
Storage temperature	-40 ... +125	°C
Power dissipation (at room temperature)	75	mW
Thermal resistance		
- Real Thermal Resistance		
Junction / ambient, R _{th JA real}	580	K/W
Junction / solder point, R _{th JS real}	330	K/W

Luminous Intensity Group at Tj=25°C

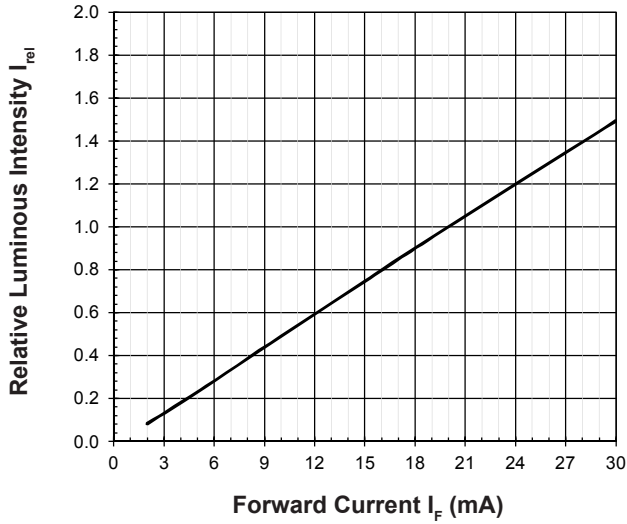
Brightness Group	Luminous Intensity <small>Appx. 1.1</small> IV (mcd)
L1	11.2 ... 14.0
L2	14.0 ... 18.0
M1	18.0 ... 22.4
M2	22.4 ... 28.5
N2	35.5 ... 45.0
P1	45.0 ... 56.0
P2	56.0 ... 71.5
Q1	71.5 ... 90.0
Q2	90.0 ... 112.5
R1	112.5 ... 140.0
R2	140.0 ... 180.0
S1	180.0 ... 224.0
S2	224.0 ... 285.0
T1	285.0 ... 355.0
T2	355.0 ... 450.0

Wavelength Grouping at Tj=25°C

Color	Group	Wavelength distribution (nm) <small>Appx. 3.1</small>
DNH; Hyper-red	Full	636 - 646
DNS; Super-red	Full	625 - 640
DNR; Red	Full	620 - 630
DNA; Amber	Full	610 - 621
	W	610 - 615
	X	615 - 621
DNO; Orange	Full	600 - 612
	W	600 - 603
	X	603 - 606
	Y	606 - 609
	Z	609 - 612
DNY; Yellow	Full	582 - 594
	W	582 - 585
	X	585 - 588
	Y	588 - 591
	Z	591 - 594
DNG; Green	Full	564.5 - 576.5
	W	564.5 - 567.5
	X	567.5 - 570.5
	Y	570.5 - 573.5
	Z	573.5 - 576.5
DNP; Pure Green	Full	552.5 - 564.5
	W	552.5 - 555.5
	X	555.5 - 558.5
	Y	558.5 - 561.5
	Z	561.5 - 564.5

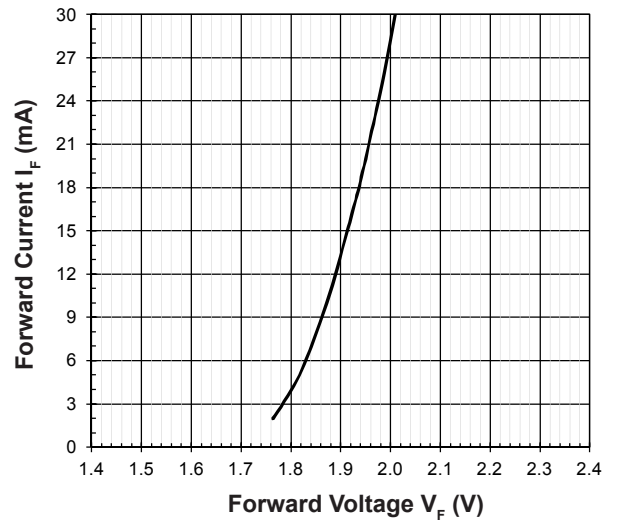
Relative Luminous Intensity Vs Forward Current *Appx. 4.1*

$I_v/I_v(20mA) = f(I_F); T_j = 25^\circ C$



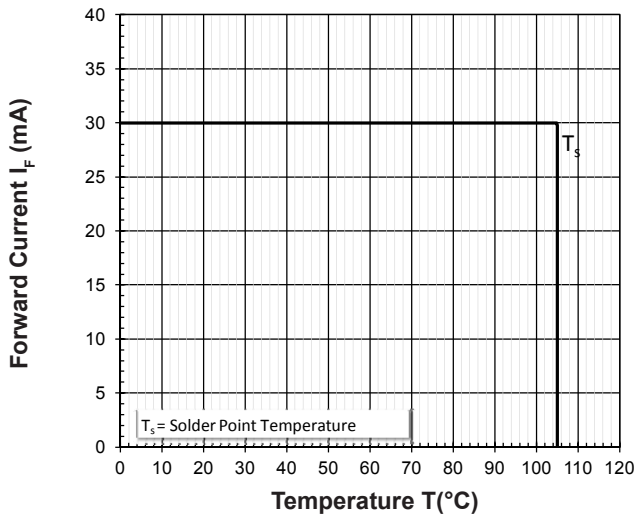
Forward Current Vs Forward Voltage *Appx. 4.1*

$I_F = f(V_F); T_j = 25^\circ C$



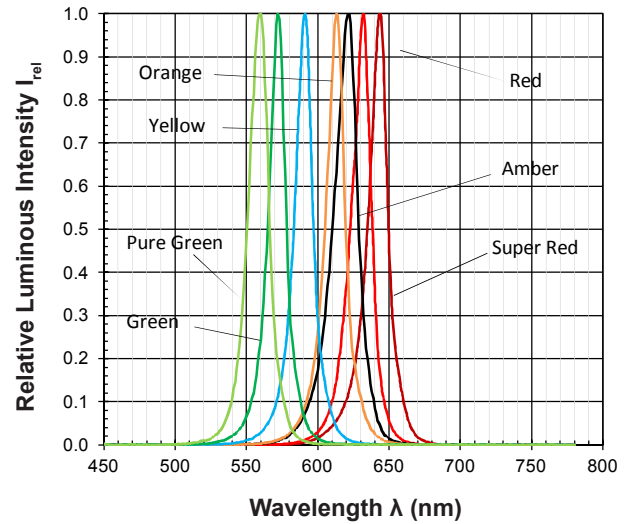
Maximum Current Vs Temperature

$I_F = f(T)$



Relative Spectral Emission *Appx. 4.1*

$I_{rel} = f(\lambda); T_j = 25^\circ C; I_F = 20mA$

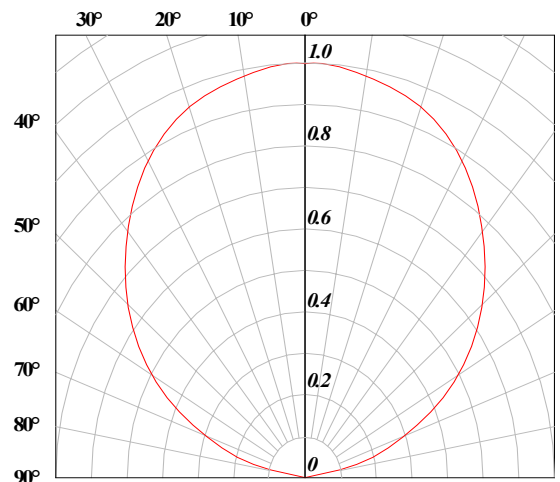


Allowable Forward Current Vs Duty Ratio

$(T_s = 55^\circ C; t_p \le 100\mu s)$

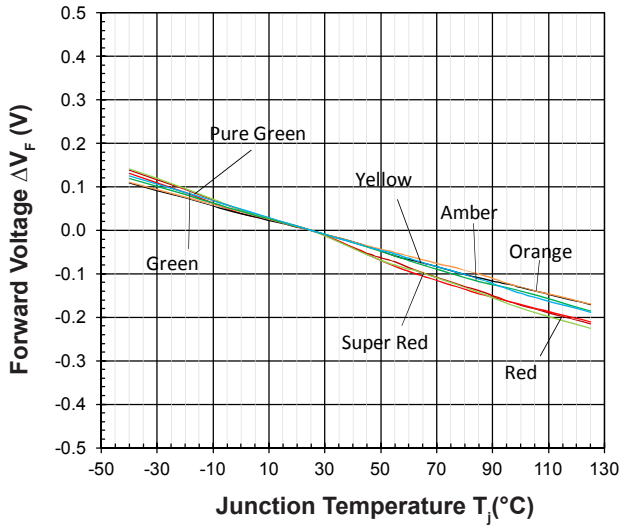


Radiation Pattern *Appx. 4.1*



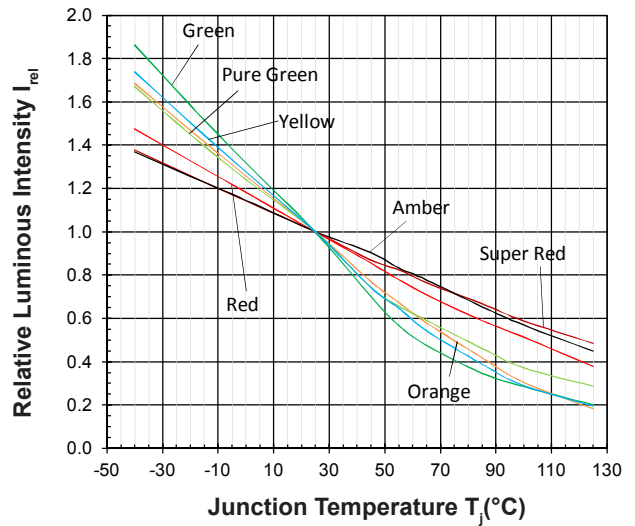
Forward Voltage Vs Junction Temperature *Appx. 4.1*

$$\Delta V_F = V_F - V_F(25^\circ\text{C}) = f(T_j); I_F = 20\text{mA}$$



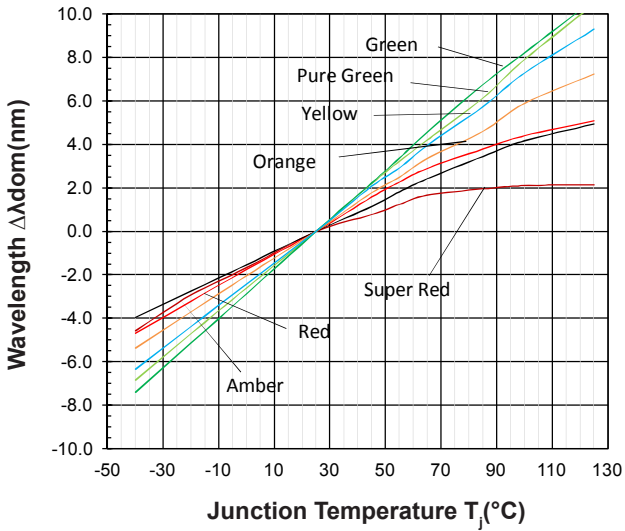
Relative Luminous Intensity Vs Junction Temperature *Appx. 4.1*

$$I_v/I_v(25^\circ\text{C}) = f(T_j); I_F = 20\text{mA}$$

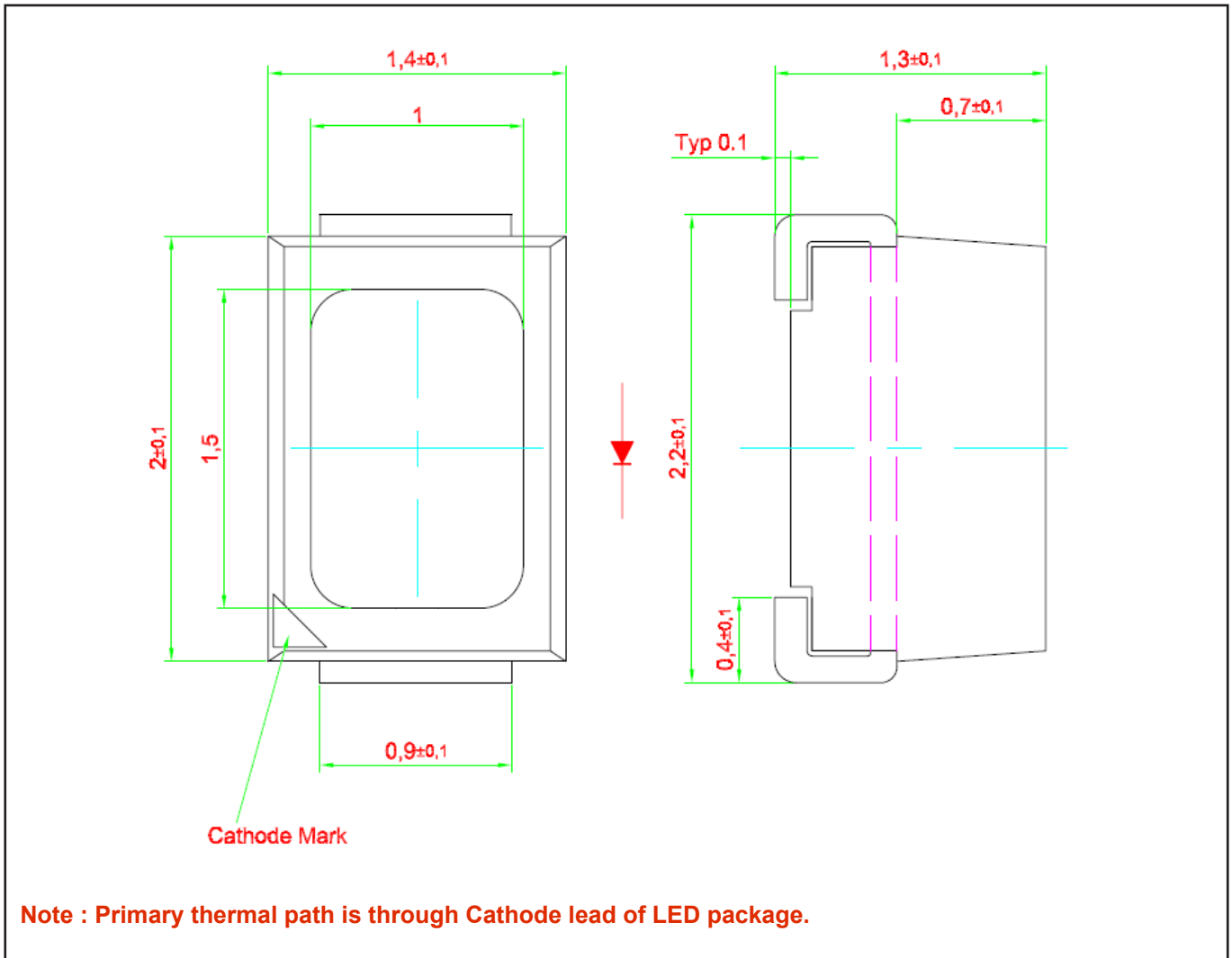


Wavelength Vs Junction Temperature *Appx. 4.1*

$$\Delta \lambda_{\text{dom}} = \lambda_{\text{dom}} - \lambda_{\text{dom}}(25^\circ\text{C}) = f(T_j); I_F = 20\text{mA}$$



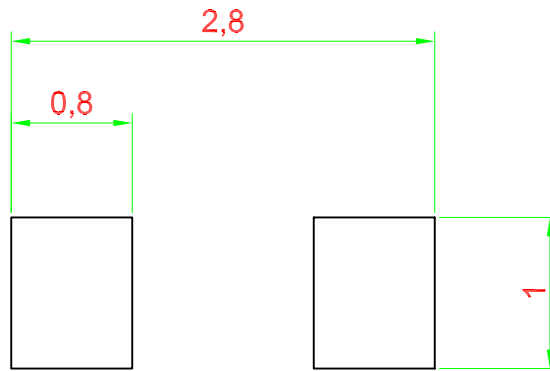
Mini DomiLED • AllnGaP : DNx-CJS Package Outlines *Appx. 5.1*



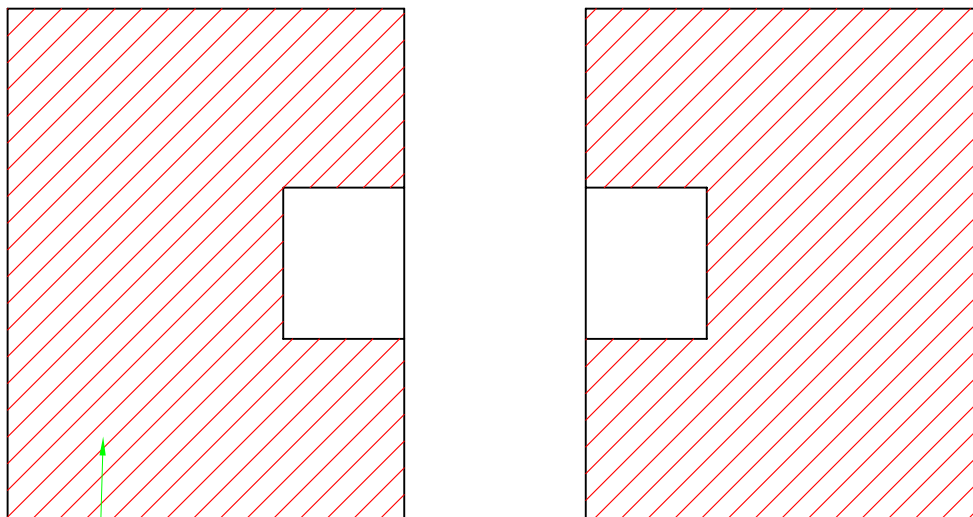
Material

Material	
Lead-frame	Cu Alloy With Ag Plating
Package	High Temperature Resistant Plastic
Encapsulant	Epoxy Resin
Soldering Leads	Sn Plating

Recommended Solder Pad *Appx. 5.1*



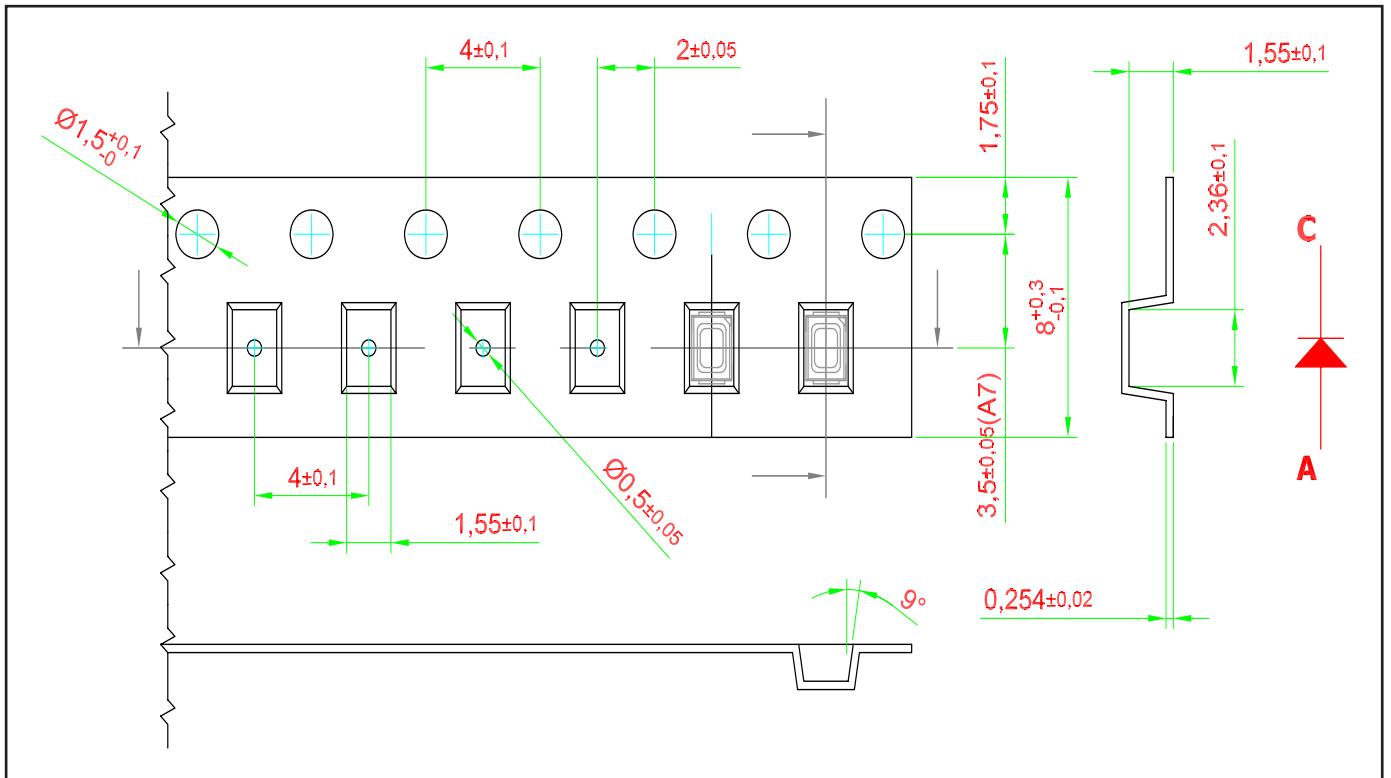
Improved Design For Better Heat Dissipation



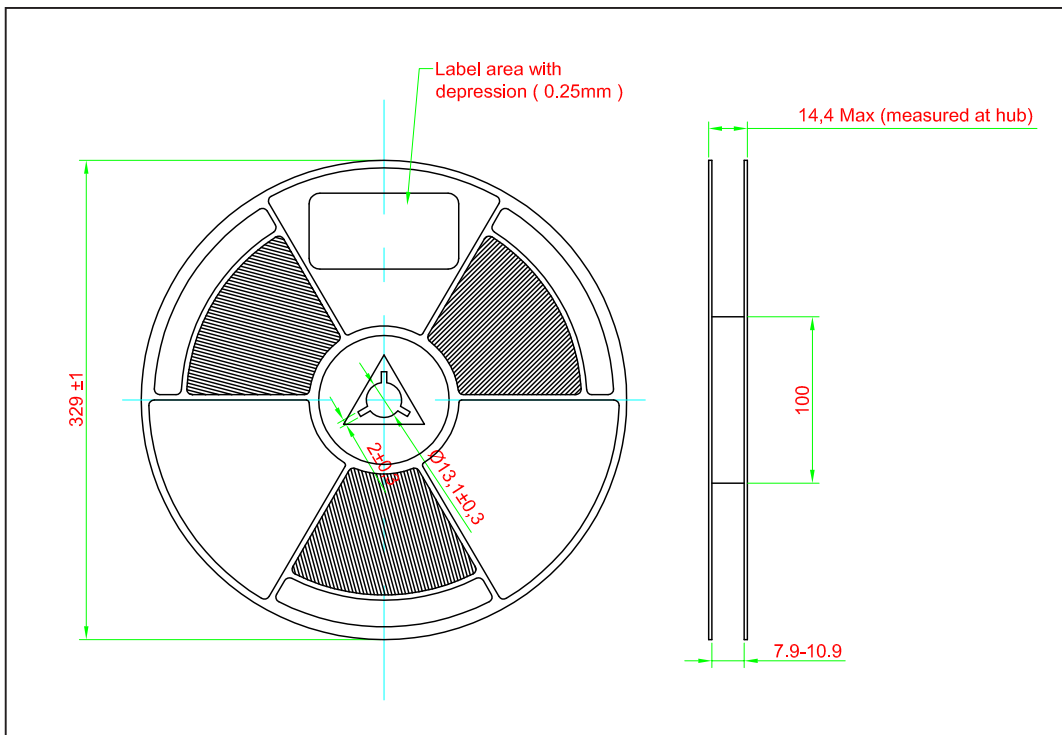
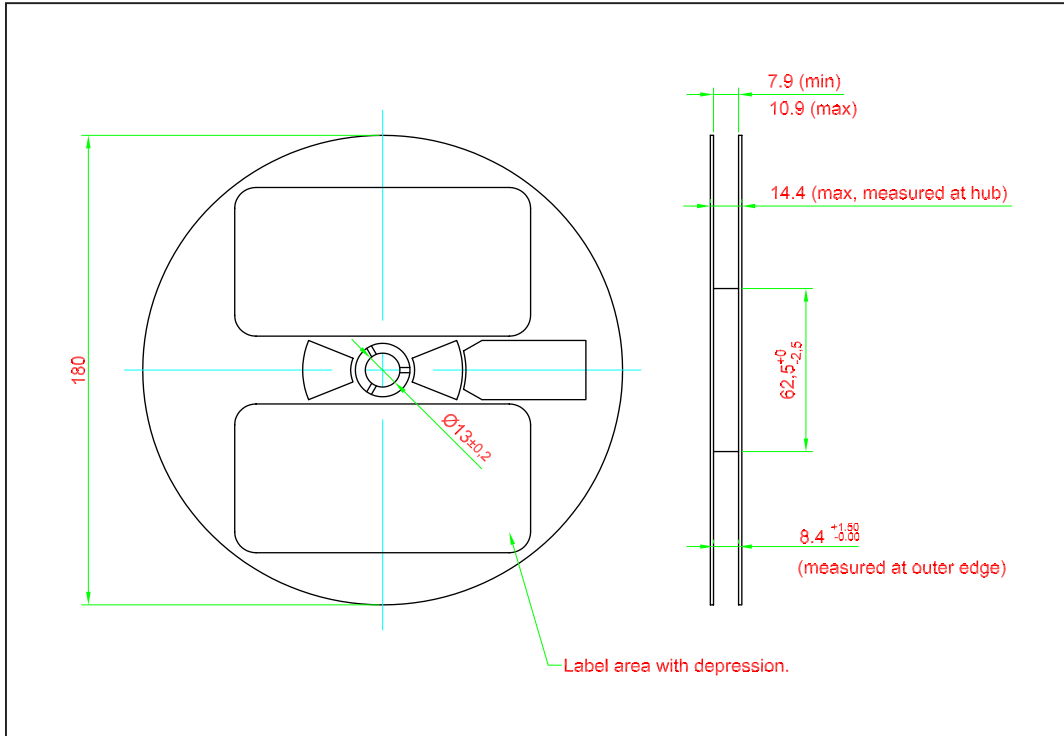
Additional Cu area for improved heat dissipation, > 16mm sq.

 Solder resist.

Taping and orientation Appx. 5.1



Packaging Specification

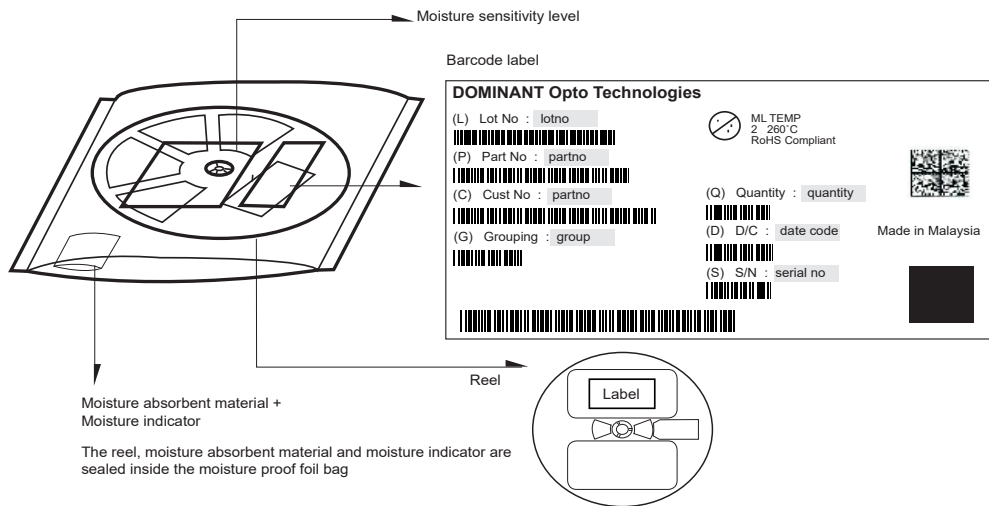


	Reel Diameter (mm)	Quantity (pcs)	*Ordering Number
Standard Packing	180	3000	DNx-CJS-xxx-x
Optional Packing	329	10000	DNx-CJS-xxx-x-J

Notes:

* For ordering purpose only. Please consult sales and marketing for details.

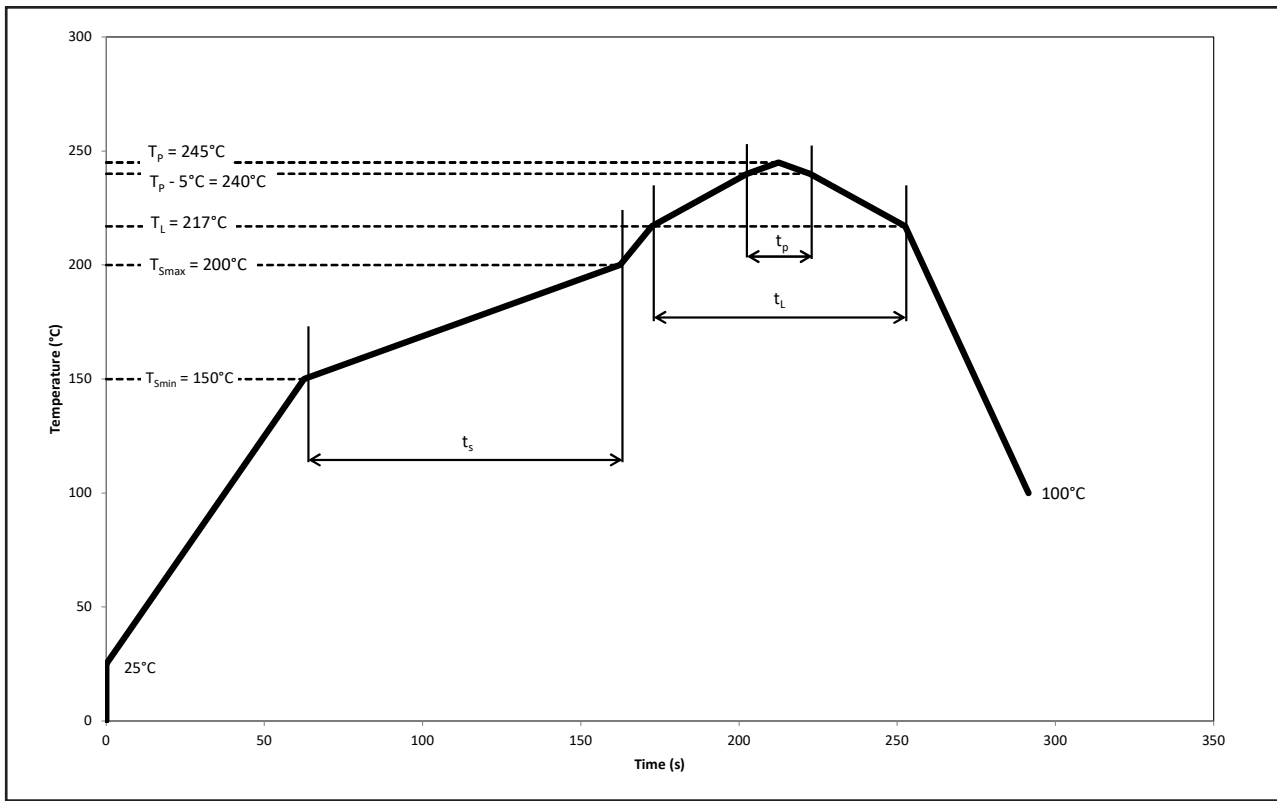
Packaging Specification



Quantity per bag (pcs)	Average 1pc Mini DomiLED (g)	1 completed bag (g)
3000	0.007	200 ± 10
10000	0.007	550 ± 10

Recommended Pb-free Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E



Profile Feature	Symbol	Pb-Free Assembly			Unit
		Min.	Recommended	Max.	
Ramp-up rate to preheat 25°C to T_{smin}	-	-	2	3	°C/s
Time t_s T_{smin} to T_{smax}	t_s	60	100	120	s
Ramp-up rate to peak T_L to T_p	-	-	2	3	°C/s
Liquidous temperature	T_L	-	217	-	°C
Time above liquidous temperature	t_L	60	80	150	s
Peak temperature	T_p	-	245	260	°C
Time within 5°C of the specified peak temperature $T_p - 5^\circ\text{C}$	t_p	10	20	30	s
Ramp-down rate T_p to 100°C	-	-	3	6	°C/s
Time 25°C to T_p	-	-	-	480	s

Appendix

1) **Brightness:**

- 1.1 Luminous intensity is measured at current pulse 25 ms(typ) with an internal reproducibility of $\pm 8\%$ and an expanded uncertainty of $\pm 11\%$ (according to GUM with a coverage factor of $k=3$).
- 1.2 Luminous flux is measured at current pulse 25 ms(typ) with an internal reproducibility of $\pm 8\%$ and an expanded uncertainty of $\pm 11\%$ (according to GUM with a coverage factor of $k=3$).
- 1.3 Radiant intensity is measured at current pulse 25 ms(typ) with an internal reproducibility of $\pm 8\%$ and an expanded uncertainty of $\pm 11\%$ (according to GUM with a coverage factor of $k=3$).
- 1.4 Radiant flux is measured at current pulse 25 ms(typ) with an internal reproducibility of $\pm 8\%$ and an expanded uncertainty of $\pm 11\%$ (according to GUM with a coverage factor of $k=3$).

2) **Color:**

- 2.1 Chromaticity coordinate groups are measured at current pulse 25 ms(typ) with an internal reproducibility of ± 0.005 and an expanded uncertainty of ± 0.01 (accordingly to GUM with a coverage factor of $k=3$).
- 2.2 Dominant wavelength is measured at current pulse 25 ms(typ) with an internal reproducibility of $\pm 0.5\text{nm}$ and an expanded uncertainty of $\pm 1\text{nm}$ (accordingly to GUM with a coverage factor of $k=3$).

3) **Voltage:**

- 3.1 Forward Voltage, V_f is measured when a current pulse of 8 ms(typ) with an internal reproducibility of $\pm 0.05\text{V}$ and an expanded uncertainty of $\pm 0.1\text{V}$ (accordingly to GUM with a coverage factor of $k=3$).

4) **Typical Values:**

- 4.1 Due to the specific conditions of semiconductor devices' manufacturing processes, the provided typical data and calculated correlations of technical parameters should only be considered as statistical values. It is important to note that the actual parameters of individual devices may deviate from these typical data, calculated correlations or the typical characteristic line. Dominant reserves the right to update this typical data without prior notice, particularly in response to technical enhancements.

5) **Tolerance of Measure**

- 5.1 Unless otherwise noted in drawing, tolerances are specified with ± 0.1 and dimension are specific in mm.

6) **Reverse Voltage:**

- 6.1 Not designed for reverse operation. Continuous reverse voltage can cause migration and LED damage.

Revision History

Page	Subjects	Date of Modification
6	Update Relative Luminous Intensity Vs Forward Current	14 Nov 2011
4	Update Characteristic	18 Jun 2012
1, 2, 12, 14	Update Features Add New Partno: DNO-CJS-S2T-1 Update Package Specification Add Appendix	28 Oct 2016
6, 7, 8	Add Electrical Thermal Resistance Update Graph Add Notes in Package Outline	07 Dec 2016
1, 14	Update Features Update Appendix	22 Jan 2018
1, 2, 6, 7, 11, 12, 13, 14	Update Features: AEC-Q101 to AEC-Q102 Update Application Not for New Design: DNH-CJS-N2Q1-1 Update Peak Pulse Current Update Operating & Storage Temperature Update Graph Update Packaging Specification Update Recommended Pb-free Soldering Profile Update Appendix	24 Dec 2020
2, 12	Not for New Design: DNS-CJS-PQ2-1, DNS-CJS-Q2S1-1, DNS-CJS-QR1-1, DNR-CJS-RS2-1, DNA-CJS-RS2-1, DNO-CJS-RS2-1, DNO-CJS-S2T-1, DNY-CJS-RS2-1, DNG-CJS-PQ2-1, DNP-CJS-LM2-1 Update Packaging Specification	03 Mar 2025

NOTE

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DOMINANT Opto Technologies reserves the right to make changes to any products in order to improve reliability, function or design.

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Dispose of product is in accordance with local, regional, national and international regulations.

About Us

DOMINANT Opto Technologies is a dynamic company that is amongst the world's leading automotive LED manufacturers. With an extensive industry experience and relentless pursuit of innovation, DOMINANT's state-of-art manufacturing and development capabilities have become a trusted and reliable brand across the globe. More information about DOMINANT Opto Technologies, an IATF 16949 and ISO 14001 certified company, can be found under <http://www.dominant-semi.com>

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